Benchmarq Products from Texas Instruments _

bq2003 **Fast-Charge IC**

Features

- ≻ Fast charge and conditioning of nickel cadmium or nickel-metal hydride batteries
- Hysteretic PWM switch-mode ≻ current regulation or gated control of an external regulator
- Easily integrated into systems ≻ or used as a stand-alone charger
- Pre-charge qualification of tem-> perature and voltage
- Direct LED outputs display > battery and charge status
- Fast-charge termination by ≻ Δ temperature/ Δ time, - Δ V, maximum voltage, maximum temperature, and maximum time
- Optional top-off charge ≻

General Description

The bg2003 Fast Charge IC provides comprehensive fast charge control functions together with high-speed switching power control circuitry on a monolithic CMOS device.

Integration of closed-loop current control circuitry allows the bq2003 to be the basis of a cost-effective solution for stand-alone and systemintegrated chargers for batteries of one or more cells.

Switch-activated discharge-beforecharge allows bq2003-based chargers to support battery conditioning and capacity determination.

High-efficiency power conversion is accomplished using the bq2003 as a hysteretic PWM controller for switch-mode regulation of the charging current. The bq2003 may alternatively be used to gate an externally regulated charging current.

Pin Names

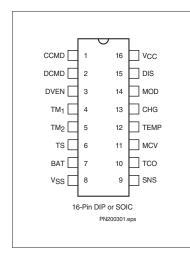
Fast charge may begin on application of the charging supply, replacement of the battery, or switch depression. For safety, fast charge is inhibited unless/until the battery temperature and voltage are within configured limits.

Temperature, voltage, and time are monitored throughout fast charge. Fast charge is terminated by any of the following:

- Rate of temperature rise $(\Delta T/\Delta t)$
- Negative delta voltage $(-\Delta V)$
- Maximum voltage
- Maximum temperature
- Maximum time

After fast charge, an optional top-off phase is available. Constant-current maintenence charge is provided by an external trickle resistor.

Pin Connections



CCMD	Charge command/select	SNS	Sense resistor input
DCMD	Discharge command	TCO	Temperature cutoff
DVEN	$-\Delta V$ enable/disable	MCV	Maximum voltage
TM_1	Timer mode select 1	TEMP	Temperature status
TM_2	Timer mode select 2		output
TS	Temperature sense	CHG	Charging status output
DAT	L	MOD	Charge current control
BAT	Battery voltage	DIS	Discharge control
V_{SS}	System ground	Vcc	$5.0V \pm 10\%$ power
		VCC	$0.01 \pm 10\%$ power

SLUS095A - OCTOBER 1999 I

Pin Descriptions

CCMD, Charge initiation and discharge-before-DCMD charge control inputs

These two inputs control the conditions that begin a new charge cycle and enable discharge-before-charge. See Table 1.

DVEN $-\Delta V$ enable input

This input enales/disables $-\Delta V$ charge termination. If DVEN is high, the $-\Delta V$ test is enabled. If DVEN is low, $-\Delta V$ test is disabled. The state of DVEN may be changed at any time.

TM₁– Timer mode inputs

 TM_2

 TM_1 and TM_2 are three-state inputs that configure the fast charge safety timer, $-\Delta V$ hold-off time, and that enhance/disable top-off. See Table 2.

TS Temperature sense input

Input, referenced to SNS, for an external thermistor monitoring battery temperature.

BAT Single-cell voltage input

The battery voltage sense input, referenced to SNS. This is created by a high-impedance resistor divider network connected between the positive and the negative terminals of the battery.

Vss Ground

SNS Charging current sense input

SNS controls the switching of MOD based on the voltage across an external sense resistor in the current path of the battery. SNS is the reference potential for the TS and BAT pins. If SNS is connected to $V_{\rm SS}$, MOD switches high at the beginning of charge and low at the end of charge.

TCO Temperature cutoff threshold input

Input to set maximum allowable battery temperature. If the potential between TS and SNS is less than the voltage at the TCO input, then fast charge or top-off charge is terminated.

MCV Maximum-Cell-Voltage threshold input

Input to set maximum single-cell equivalent voltage. If the voltage between BAT and SNS is greater than or equal to the voltage at the MCV input, then fast charge or top-off charge is inhibited.

Note: For valid device operation, the voltage level on MCV must not exceed $0.6 * V_{\rm CC}$.

TEMP Temperature status output

Push-pull output indicating temperature status. TEMP is low if the voltage at the TS pin is not within the allowed range to start fast charge.

CHG Charging status output

Push-pull output indicating charging status. See Figure 1.

MOD Current-switching control output

MOD is a push/pull output that is used to control the charging current to the battery. MOD switches high to enable charging current flow and low to inhibit charging current flow.

DIS Discharge FET control output

Push-pull output used to control an external transistor to discharge the battery before charging.

V_{CC} supply input

5.0 V, ±10% power input.

Vcc

Functional Description

Figure 3 shows a state diagram and Figure 4 shows a block diagram of the bq2003.

Battery Voltage and Temperature Measurements

Battery voltage and temperature are monitored for maximum allowable values. The voltage presented on the battery sense input, BAT, should represent a single-cell potential for the battery under charge. A resistor-divider ratio of:

$$\frac{\text{RB1}}{\text{RB2}} = \text{N} - 1$$

is recommended to maintain the battery voltage within the valid range, where N is the number of cells, RB1 is the resistor connected to the positive battery terminal, and RB2 is the resistor connected to the negative battery terminal. See Figure 1.

Note: This resistor-divider network input impedance to end-to-end should be at least $200k\Omega$ and less than $1M\Omega$.

A ground-referenced negative temperature coefficient thermistor placed in proximity to the battery may be used as a low-cost temperature-to-voltage transducer. The temperature sense voltage input at TS is developed using a resistor-thermistor network between $V_{\rm CC}$ and battery's negative terminal See Figure 1. Both the BAT and TS inputs are referenced to SNS, so the signals used inside the IC are:

 V_{BAT} - V_{SNS} = V_{CELL}

and

 V_{TS} - V_{SNS} = V_{TEMP}

Table 1. New Charge Cycle and Discharge Stimulus

CCMD Pulled Up	DCMD /Down to:	New Charge Cycle Started by:	Discharge-Before-Charge Started by:
		V _{CC} rising to valid level	
$\mathbf{V}_{\mathbf{SS}}$	$V_{\rm SS}$	$\begin{array}{c} Battery \ replacement \\ (V_{CELL} \ falling \ through \ V_{MCV}) \end{array}$	A rising edge on DCMD
		A rising edge on CCMD	
		V _{CC} rising to valid level	
$V_{\rm CC}$	V _{CC}	$\begin{array}{c} Battery \ replacement \\ (V_{CELL} \ falling \ through \ V_{MCV}) \end{array}$	A rising edge on DCMD
		A falling edge on CCMD or DCMD	
V _{CC}	V _{SS}	A rising edge on CCMD	A rising edge on DCMD
V_{SS}	V _{CC}	A falling edge on CCMD	A rising edge on DCMD

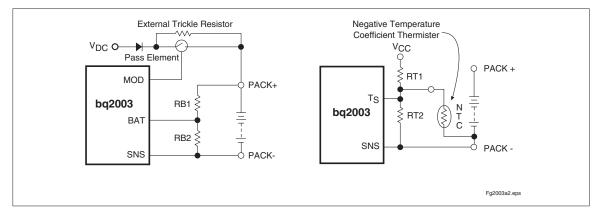


Figure 1. Voltage and Temperature Monitoring and Trickle Resistor

Discharge-Before-Charge

The DCMD input is used to command discharge-beforecharge via the DIS output. Once activated, DIS becomes active (high) until V_{CELL} falls below V_{EDV}, at which time DIS goes low and a new fast charge cycle begins. See Table 1 for the conditions that initiate discharge-beforecharge. Discharge-before-charge is qualified by the same voltage and temperature conditions that qualify a new charge cycle start (see below). If a discharge is initiated but the pack voltage or temperature is out of range, the chip enters the charge pending mode and trickle charges the battery until the voltage and temperature qualification conditions are met, and then starts to discharge.

Starting A Charge Cycle

The stimulus required to start a new charge cycle is determined by the configuration of the CCMD and DCMD inputs. If CCMD and DCMD are both pulled up or pulled down, then a new charge cycle is started by (see Figure 2):

- 1. V_{CC} rising above 4.5V
- 2. V_{CELL} falling through the maximum cell voltage, V_{MCV} . V_{MCV} is the voltage presented at the MCV input pin, and is configured by the user with a resistor divider between V_{CC} and ground. The allowed range is 0.2 to 0.4 * V_{CC} .

3. A rising edge on CCMD if it is pulled down, or a falling edge on CCMD if it is pulled up.

Starting a new charge cycle may be limited to a pushbutton or logical pulse input only by pulling one member of the DCMD and CCMD pair up while pulling the other input down. In this configuration a new charge cycle will be started only by a falling edge on CCMD if it is pulled up, and by a falling edge on CCMD if it is pulled down. See Table 1.

If the battery is within the configured temperature and voltage limits, the IC begins fast charge. The valid battery voltage range is $V_{\rm EDV} < V_{\rm BAT} < V_{\rm MCV}$ where:

$$V_{EDV} = 0.2 * V_{CC} \pm 30 mV$$

The valid temperature range is $V_{\rm HTF} < V_{\rm TEMP} < V_{\rm LTF},$ where:

$$V_{LTF} = 0.4 * V_{CC} \pm 30 mV$$

 $V_{HTF} = [(1/8 * V_{LTF}) + (7/8 * V_{TCO})] \pm 30 \text{mV}$

 V_{TCO} is the voltage presented at the TCO input pin, and is configured by the user with a resistor divider between V_{CC} and ground. The allowed range is 0.2 to 0.4 * V_{CC} .

If the temperature of the battery is out of range, or the voltage is too low, the chip enters the charge pending state and waits for both conditions to fall within their allowed limits. There is no time limit on the charge pending state; the charger remains in this state as long as the voltage or temperature conditons are outside of

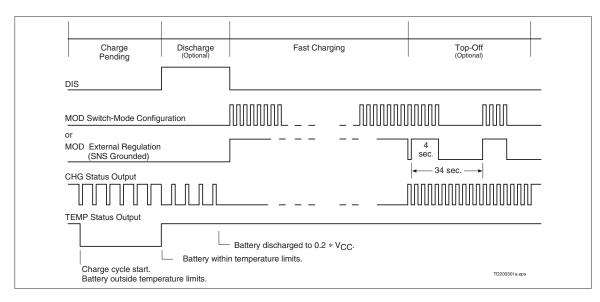


Figure 2. Charge Cycle Phases

Table 2. Fast-Charge Safety Time/Hold-Off/Top-Off Table									
Corresponding Fast-Charge Rate	TM1	TM2	Typical Fast Charge and Top-Off Time Limits	Typical -∆V/MCV Hold-Off Time (seconds)	Top-Off Rate				
C/4	Low	Low	360	137	Disabled				
C/2	Float	Low	180	820	Disabled				
1C	High	Low	90	410	Disabled				
2C	Low	Float	45	200	Disabled				
$4\mathrm{C}$	Float	Float	23	100	Disabled				
C/2	High	Float	180	820	C/16				
1C	Low	High	90	410	C/8				
$2\mathrm{C}$	Float	High	45	200	C/4				
$4\mathrm{C}$	High	High	23	100	C/2				

Table 2. Fast-Charge Safety Time/Hold-Off/Top-Off Table

Note: Typical conditions = 25° C, V_{CC} = 5.0V.

the allowed limits. If the voltage is too high, the chip goes to the battery absent state and waits until a new charge cycle is started.

Fast charge continues until termination by one or more of the five possible termination conditions:

- **Delta temperature/delta time** $(\Delta T/\Delta t)$
- Negative delta voltage (-∆V)
- Maximum voltage
- Maximum temperature
- Maximum time

- **V** Termination

If the DVEN input is high, the bq2003 samples the voltage at the BAT pin once every 34s. If V_{CELL} is lower than any previously measured value by 12mV ±4mV, fast charge is terminated. The - Δ V test is valid in the range V_{MCV}-(0.2 * V_{CC}) < V_{CELL} < V_{MCV}.

Voltage Sampling

Each sample is an average of 16 voltage measurements taken $57\mu s$ apart. The resulting sample period (18.18ms) filters out harmonics around 55Hz. This technique minimizes the effect of any AC line ripple that may feed through the power supply from either 50Hz or 60Hz AC sources. Tolerance on all timing is $\pm 16\%$.

Voltage Termination Hold-off

A hold-off period occurs at the start of fast charging. During the hold-off period, $-\Delta V$ termination is disabled. This avoids premature termination on the voltage spikes sometimes produced by older batteries when fast-charge current is first applied. $\Delta T/\Delta t$, maximum voltage and maximum temperature terminations are not affected by the hold-off period.

∆T/∆t Termination

The bq2003 samples at the voltage at the TS pin every 34s, and compares it to the value measured two samples earlier. If V_{TEMP} has fallen 16mV ±4mV or more, fast charge is terminated. The Δ T/ Δ t termination test is valid only when V_{TCO} < V_{TEMP} < V_{LTF}.

Temperature Sampling

Each sample is an average of 16 voltage measurements taken $57\mu s$ apart. The resulting sample period (18.18ms) filters out harmonics around 55Hz. This technique minimizes the effect of any AC line ripple that may feed through the power supply from either 50Hz or 60Hz AC sources. Tolerance on all timing is $\pm 16\%$.

Maximum Voltage, Temperature, and Time

Anytime $V_{\rm CELL}$ rises above $V_{\rm MCV},$ CHG goes high (the LED goes off) immediately. If the bq2003 is not in the voltage hold-off period, fast charging ceases if $V_{\rm CELL}$ remains above MCV for a minimum of $t_{\rm MCV}$. If $V_{\rm CELL}$ then falls back below $V_{\rm MCV}$ before $1.5 t_{\rm MCV} \pm 50 {\rm ms}$, the chip transitions to the Charge Complete state (maximum voltage termination). If $V_{\rm CELL}$ remains above $V_{\rm MCV}$ beyond $1.5 t_{\rm MCV}$, the bq2003 transitions to the Battery Absent state (battery removal). See Figure 3.

If the bq2003 is in the voltage hold-off period when V_{CELL} rises above V_{MCV} , the LED goes out but fast charging continues until the expiration of the hold-off period. Temperature sampling continues during the hold-off period as well. If a new battery is inserted before the hold-off period expires, it continues in the fast charge cycle started by its predecessor. No precharge qualification is performed, and a temperature sample

taken on the new battery is compared to ones taken before the original battery was removed and any that may have been taken while no battery was present. If the IC is configured for $\Delta T/\Delta t$ termination, this may result in a premature fast-charge termination on the newly inserted battery.

Maximum temperature termination occurs anytime the voltage on the TS pin falls below the temperature cut-off threshold V_{TCO} . Charge is also terminated if V_{TEMP} rises above the minimum temperature fault threshold, V_{LTF} , after fast charge begins.

Maximum charge time is configured using the TM pin. Time settings are available for corresponding charge rates of C/4, C/2, 1C, and 2C. Maximum time-out termination is enforced on the fast-charge phase, then reset, and enforced again on the top-off phase, if selected. There is no time limit on the trickle-charge phase.

Top-off Charge

An optional top-off charge phase may be selected to follow fast charge termination for the C/2 through 4C rates. This phase may be necessary on NiMH or other battery chemistries that have a tendency to terminate charge prior to reaching full capacity. With top-off enabled, charging continues at a reduced rate after fast-charge termination for a period of time selected by the TM₁ and TM₂ input pins. (See Table 2.) During top-off, the MOD pin is enabled at a duty cycle of 4s active for every 30s inactive. This modulation results in an average rate 1/8th that of the fast charge rate. Maximum voltage, time, and temperature are the only termination methods enabled during top-off.

External Trickle Resistor

Maintenance charging is provided by the use of an external trickle resistor between the high side of the battery pack and V_{DC} , the input charging supply voltage. (See Figure 1.) This resistor is sized to meet two criteria.

- With the battery removed, the resistor must pull the voltage at the BAT input above MCV for battery insertion and removal detection.
- With the battery at its fully charged voltage, the trickle current should be approximately equal to the self-discharge rate of the battery.

Charge Status Indication

Charge status is indicated by the CHG output. The state of the CHG output in the various charge cycle phases is shown in Figure 3 and illustrated in Figure 1.

Temperature status is indicated by the TEMP output. TEMP is in the high state whenever V_{TEMP} is within the temperature window defined by the V_{LTF} and V_{HTF} temperature limits, and is low when the battery temperature is outside these limits.

In all cases, if V_{CELL} exceeds the voltage at the MCV pin, both CHG and TEMP outputs are held high regardless of other conditions. CHG and TEMP may both be used to directly drive an LED.

Charge Current Control

The bq2003 controls charge current through the MOD output pin. The current control circuitry is designed to support implementation of a constant-current switching regulator or to gate an externally regulated current source.

When used in switch-mode configuration, the nominal regulated current is:

$I_{REG} = 0.235 V/R_{SNS}$

Charge current is monitored at the SNS input by the voltage drop across a sense resistor, $R_{\rm SNS}$, between the low side of the battery pack and ground. $R_{\rm SNS}$ is sized to provide the desired fast-charge current.

If the voltage at the SNS pin is less than $V_{\rm SNSLO}$, the MOD output is switched high to pass charge current to the battery.

When the SNS voltage is greater than $V_{\rm SNSHI}$, the MOD output is switched low—shutting off charging current to the battery.

$$V_{SNSLO} = 0.044 * V_{CC} \pm 25 mV$$

 $V_{SNSHI} = 0.05 * V_{CC} \pm 25 mV$

When used to gate an externally regulated current source, the SNS pin is connected to $V_{\rm SS},$ and no sense resisitor is required.

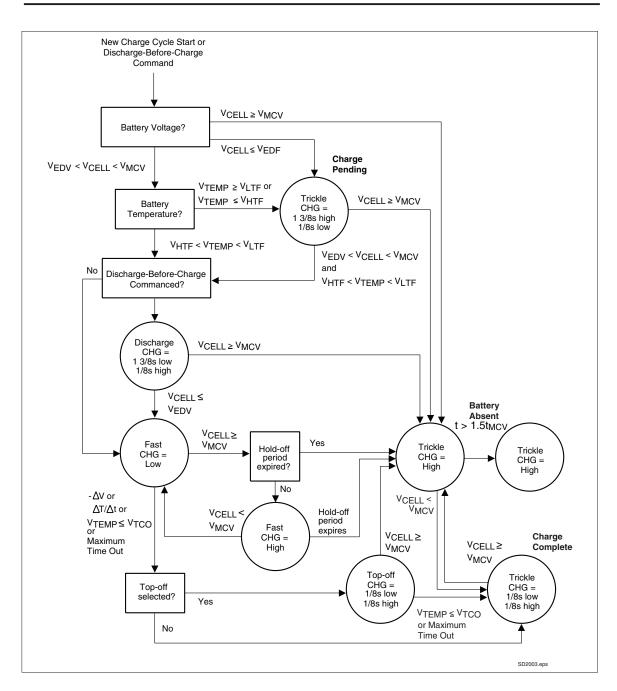


Figure 3. State Diagram

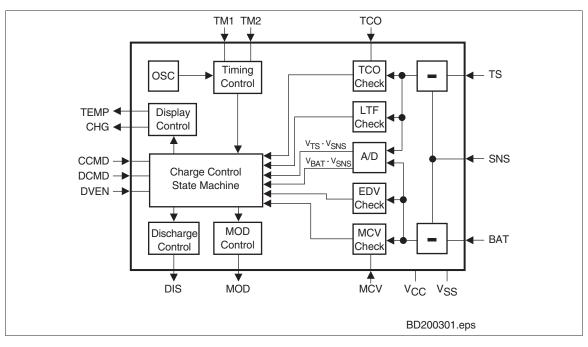


Figure 4. Block Diagram

Symbol	Parameter	Minimum	Maximum	Unit	Notes
V _{CC}	$V_{\rm CC}$ relative to $V_{\rm SS}$	-0.3	+7.0	V	
VT	DC voltage applied on any pin excluding V_{CC} relative to V_{SS}	-0.3	+7.0	v	
TOPR	Operating ambient temperature	0	+70	°C	Commercial
T _{STG}	Storage temperature	-55	+125	°C	
TSOLDER	Soldering temperature	-	+260	°C	10 sec max.
T _{BIAS}	Temperature under bias	-40	+85	°C	

Absolute Maximum Ratings

Note: Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

DC Thresholds (TA = TOPR; VCC ±10%)

Symbol	Parameter	Rating	Tolerance	Unit	Notes
V _{SNSHI}	High threshold at SNS re- sulting in MOD = Low	$0.05 * V_{CC}$	± 0.025	V	Tolerance is common mode deviation.
V _{SNSLO}	Low threshold at SNS re- sulting in MOD = High	$0.044 * V_{CC}$	± 0.025	V	Tolerance is common mode deviation.
V _{LTF}	Low-temperature fault	$0.4 * V_{CC}$	± 0.030	V	$V_{TEMP} \geq V_{LTF} \text{ inhibits/} \\ terminates charge}$
V _{HTF}	High-temperature fault	$(1/8 * V_{LTF}) + (7/8 * V_{TCO})$	± 0.030	V	V _{TEMP} ≤ V _{HTF} inhibits fast charge
V _{EDV}	End-of-discharge voltage	$0.2 * V_{\rm CC}$	± 0.030	V	V _{CELL} < V _{EDV} inhibits fast charge
V _{THERM}	TS input change for ΔT/Δt detection	-16	±4	mV	V_{CC} = 5V, T_A = 25°C
-ΔV	BAT input change for $-\Delta V$ detection	-12	± 4	mV	V_{CC} = 5V, T_A = 25°C

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Notes
V _{CC}	Supply voltage	4.5	5.0	5.5	V	
VBAT	Battery input	0	-	V _{CC}	V	
V _{CELL}	BAT voltage potential	0	-	V _{CC}	V	V _{BAT} - V _{SNS}
V _{TS}	Thermistor input	0	-	V _{CC}	V	
VTEMP	TS voltage potential	0	-	Vcc	V	VTS - VSNS
V _{MCV}	Maximum cell voltage	$0.2 * V_{\rm CC}$	-	$0.4 * V_{CC}$	V	
V _{TCO}	Temperature cutoff	$0.2 * V_{\rm CC}$	-	$0.4 * V_{CC}$	V	
37	Logic input high	V _{CC} - 1.0	-	-	V	CCMD, DCMD, DVEN
V _{IH}	Logic input high	V _{CC} - 0.3	-	-	V	$\mathrm{TM}_1,\mathrm{TM}_2$
37	Logic input low	-	-	1.0	V	CCMD, DCMD, DVEN
VIL	Logic input low	-	-	0.3	V	$\mathrm{TM}_1,\mathrm{TM}_2$
VOH	Logic output high	V _{CC} - 0.5	-	-	V	DIS, TEMP, CHG, MOD, $I_{OH} \leq -5mA$
Vol	Logic output low	-	-	0.5	V	DIS, TEMP, CHG, MOD, $I_{OL} \le 5mA$
ICC	Supply current	-	0.75	2.2	mA	Outputs unloaded
I _{OH}	DIS, TEMP, MOD, CHG source	-5.0	-	-	mA	$@V_{OH} = V_{CC} - 0.5V$
I _{OL}	DIS, TEMP, MOD, CHG sink	5.0	-	-	mA	$@V_{OL} = V_{SS} + 0.5V$
т	Input leakage	-	-	± 1	μΑ	CCMD, DCMD, DVEN, $V = V_{SS}$ to V_{CC}
I _{IL}	Logic input low source	-	-	70	μΑ	$\begin{array}{l} TM_1, TM_2, \\ V = V_{SS} \text{ to } V_{SS} + 0.3V \end{array}$
I _{IH}	Logic input high source	-70	-	-	μΑ	$\begin{array}{l} TM_1, TM_2, \\ V = V_{CC} \text{ - } 0.3V \text{ to } V_{CC} \end{array}$
I_{IZ}	TM ₁ , TM ₂ tri-state open detection	-2.0	-	2.0	μΑ	TM_1, TM_2 may be left disconnected (floating) for Z logic input state

Recommended DC Operating Conditions (TA = 0 to +70°C)

Note: All voltages relative to $V_{\rm SS}\, except$ as noted.

Impedance

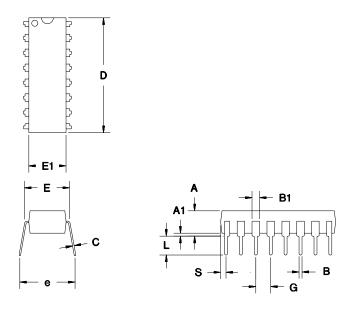
Symbol	Parameter	Minimum	Typical	Maximum	Unit
R _{BAT}	Battery input impedance	50	-	-	MΩ
R _{MCV}	MCV input impedance	50	-	-	ΜΩ
R _{TCO}	TCO input impedance	50	-	-	MΩ
R _{SNS}	SNS input impedance	50	-	-	MΩ
R _{TS}	TS input impedance	50	-	-	MΩ

Timing (TA = 0 to +70°C; VCC \pm 10%)

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Notes
$t_{\rm PW}$	Pulse width for CCMD, DCMD pulse commands	1	-	-	μs	Pulse start for charge or discharge- before-charge
$d_{\rm FCV}$	Time base variation	-16	-	16	%	V_{CC} = 4.5V to 5.5V
$\mathbf{f}_{\mathrm{REG}}$	MOD output regulation frequency	-	-	300	kHz	
$t_{ m MCV}$	Maximum voltage termination time limit	200	250	300	ms	Time limit to distinguish battery re- moved from charge complete

Note: Typical is at $T_A = 25^{\circ}C$, $V_{CC} = 5.0V$.

PN: 16-Pin DIP Narrow

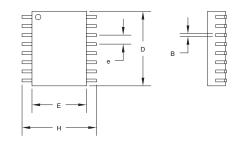


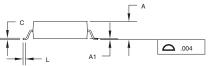
Dimension	Minimum	Maximum
Α	0.160	0.180
A1	0.015	0.040
В	0.015	0.022
B1	0.055	0.065
С	0.008	0.013
D	0.740	0.770
E	0.300	0.325
E1	0.230	0.280
е	0.300	0.370
G	0.090	0.110
L	0.115	0.150
S	0.020	0.040

16-Pin PN (DIP Narrow)

All dimensions are in inches.

S: 16-Pin SOIC





16-Pin S (SOIC)

Dimension	Minimum	Maximum
Α	0.095	0.105
A1	0.004	0.012
В	0.013	0.020
С	0.008	0.013
D	0.400	0.415
E	0.290	0.305
е	0.045	0.055
Н	0.395	0.415
L	0.020	0.040

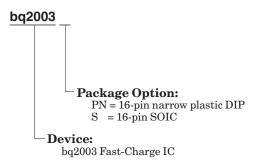
All dimensions are in inches.

Change No.	Page No.	Description	Nature of Change
5	2	Changed block diagram	Changed diagram.
5	8	Added top-off values to Table 2.	Added values.
6	All	Revised and expanded format of this data sheet	Clarification
7	9	T _{OPR}	Deleted industrial temperature range.
8	3	Corrected Table 1	Correction
8	5, 7	Corrected and expanded the explanation for maxi- mum voltage conditions	Clarification

Data Sheet Revision History

Notes: Changes 1–4: Please refer to the 1997 Data Book. Change 5 = Sept. 1996 F changes from Oct. 1993 E. Change 6 = Oct. 1997 G changes from Sept. 1996 F. Change 7 = June 1999 H changes from Oct. 1997 G. Change 8 = Oct. 1999 I changes from June 1999 H.

Ordering Information



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL AP-PLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WAR-RANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1999, Texas Instruments Incorporated



6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	-	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		•		Qty	(2)	(6)	(3)		(4/5)	
BQ2003PN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	0 to 70	2003PN	Samples
BQ2003PN-N	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	-40 to 85	2003PN-N	Samples
BQ2003PNE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	NIPDAU	N / A for Pkg Type	0 to 70	2003PN	Samples
BQ2003S	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2003S	Samples
BQ2003S-N	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2003S-N	Samples
BQ2003S-NG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2003S-N	Samples
BQ2003S-NTR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2003S-N	Samples
BQ2003S-NTRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2003S-N	Samples
BQ2003SG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2003S	Samples
BQ2003STR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2003S	Samples
BQ2003STRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	2003S	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS**: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.



6-Feb-2020

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*A	Il dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	BQ2003S-NTR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
	BQ2003STR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

12-Feb-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
BQ2003S-NTR	SOIC	DW	16	2000	350.0	350.0	43.0
BQ2003STR	SOIC	DW	16	2000	350.0	350.0	43.0

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2020, Texas Instruments Incorporated